**Product data sheet** 

# 1. General description

NPN low V<sub>CEsat</sub> transistor in a SOT89 (SC-62) medium power and flat lead plastic package.

PNP complement: PBSS5480X

### 2. Features and benefits

- High h<sub>FE</sub> and low V<sub>CEsat</sub> at high current operation
- High collector current capability: I<sub>C</sub> maximum 4 A
- High efficiency leading to less heat generation
- Qualified according to AEC-Q101 and recommended for use in automotive applications

# 3. Applications

- · Medium power peripheral drivers; e.g. fan, motor
- · Strobe flash units for DSC and mobile phones
- · Inverter applications; e.g. TFT displays
- Power switch for LAN and ADSL systems
- Medium power DC-to-DC conversion
- Battery chargers

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	80	V
I <sub>C</sub>	collector current		[1]	-	-	4	Α
I <sub>CM</sub>	peak collector current	limited by $T_{j(max)}$ ; single pulse; $t_p \le 1 \text{ ms}$		-	-	10	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = 5 A; $I_B$ = 500 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C		-	40	54	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		С
2	С	collector		
3	В	base	3 2 1	B —
			SOT89	sym123

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package		
	Name	Description	Version
PBSS4480X-Q		plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS4480X-Q	%1Y

[1] % = placeholder for manufacturing site code

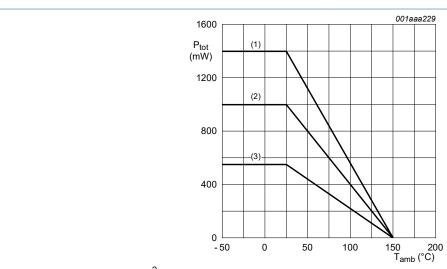
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	80	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	80	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
I <sub>C</sub>	collector current		[1]	-	4	Α
I <sub>CRM</sub>	repetitive peak collector current	t <sub>p</sub> ≤ 10 ms		-	6	А
I <sub>CM</sub>	peak collector current	limited by $T_{j(max)}$ ; single pulse; $t_p \le 1$ ms		-	10	Α
I <sub>B</sub>	base current			-	1	Α
I <sub>BM</sub>	peak base current	single pulse; $t_p \le 300 \mu s$		-	2	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2] [3]	-	2.5	W
			[2]	-	550	mW
			[4]	-	1	W
			[1]	-	1.4	W
			[5]	-	1.6	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [2] [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Operated under pulsed conditions;  $t_p \le 10$  ms;  $\delta \le 0.2$ .
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- Device mounted on a 7 cm<sup>2</sup> ceramic PCB, 1 cm<sup>2</sup> single-sided copper and tin-plated. [5]



- (1) FR4 PCB; 6 cm<sup>2</sup> mounting pad for collector (2) FR4 PCB; 1 cm<sup>2</sup> mounting pad for collector
- (3) FR4; standard footprint

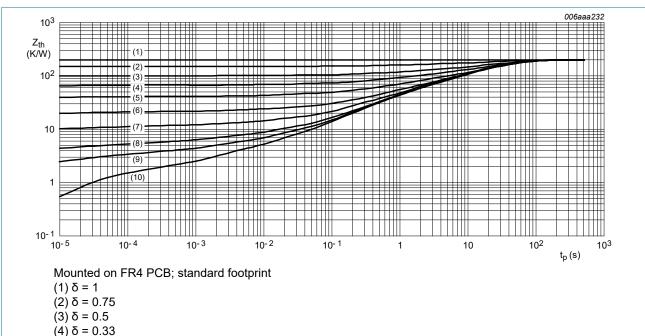
**Power derating curves** Fig. 1.

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	[1] [3] [4]	[1] [2]	-	-	50	K/W
	junction to ambient		[1]	-	-	225	K/W
			[3]	-	-	125	K/W
			[4]	-	-	90	K/W
			[5]	-	-	80	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	16	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Operated under pulsed conditions;  $t_p \le 10$  ms;  $\delta \le 0.2$ .
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup> [3]
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- Device mounted on a 7 cm<sup>2</sup> ceramic PCB, 1 cm<sup>2</sup> single-sided copper and tin-plated.



 $(5) \delta = 0.2$ 

 $(6) \delta = 0.1$ 

 $(7) \delta = 0.05$ 

 $(8) \delta = 0.02$ 

 $(9) \delta = 0.01$ 

 $(10) \delta = 0$ 

Transient thermal impedance as a function of pulse duration; typical values

#### 80 V, 4 A NPN low VCEsat transistor

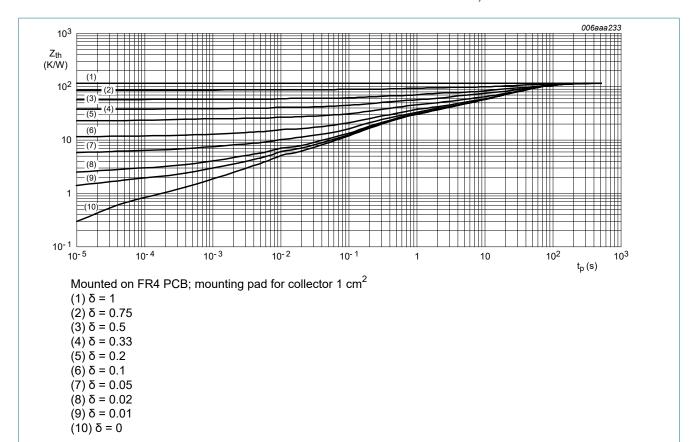
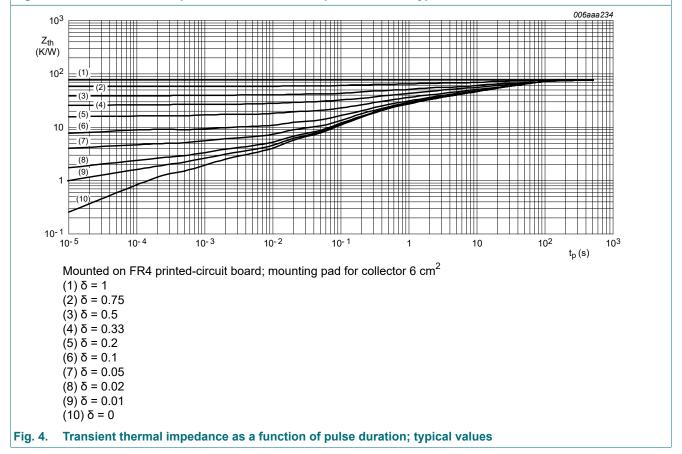


Fig. 3. Transient thermal impedance as a function of pulse duration; typical values



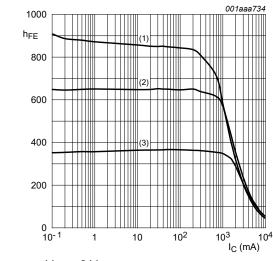
80 V, 4 A NPN low VCEsat transistor

# 10. Characteristics

### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = 80 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
	current	V <sub>CB</sub> = 80 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>CE</sub> = 80 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 0.5 A; T <sub>amb</sub> = 25 °C	250	400	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 1 A; pulsed; $t_{p}$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	250	400	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 2 A; pulsed; $t_{p}$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	175	270	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 4 A; pulsed; $t_{p}$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	80	140	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 0.5 \text{ A}; I_B = 50 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	25	40	mV
		I <sub>C</sub> = 1 A; I <sub>B</sub> = 50 mA; T <sub>amb</sub> = 25 °C	-	55	80	mV
		I <sub>C</sub> = 2 A; I <sub>B</sub> = 40 mA; T <sub>amb</sub> = 25 °C	-	110	160	mV
		$I_C$ = 4 A; $I_B$ = 200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	170	230	mV
		$I_C = 5 \text{ A}$ ; $I_B = 500 \text{ mA}$ ; pulsed; $t_p \le$	-	200	270	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	40	54	mΩ
V <sub>BEsat</sub>	base-emitter saturation	$I_C = 0.5 \text{ A}; I_B = 50 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	0.78	0.85	V
	voltage	I <sub>C</sub> = 1 A; I <sub>B</sub> = 50 mA; T <sub>amb</sub> = 25 °C	-	0.79	0.9	V
		$I_C$ = 1 A; $I_B$ = 100 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	0.82	0.95	V
		$I_C$ = 4 A; $I_B$ = 400 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	0.95	1.05	V
$V_{BEon}$	base-emitter turn-on voltage	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 2 A; T <sub>amb</sub> = 25 °C	-	0.78	0.85	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 10 V; I <sub>C</sub> = 100 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	120	150	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 ^{\circ}\text{C}$	-	35	50	pF

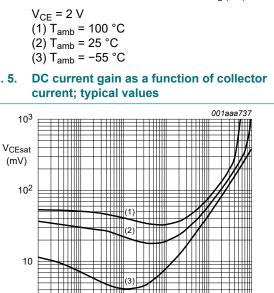
#### 80 V, 4 A NPN low VCEsat transistor



$$V_{CF} = 2 V$$

$$(1) T_{amb} = 100 ° ($$

Fig. 5. current; typical values



- $(1) I_C/I_B = 100$
- (2)  $I_C/I_B = 50$

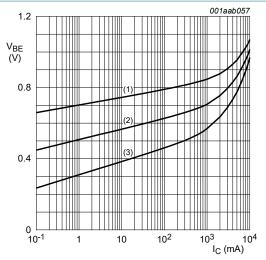
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(3)  $I_C/I_B = 10$ 

Collector-emitter saturation voltage as a Fig. 7. function of collector current; typical values

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10<sup>2</sup>

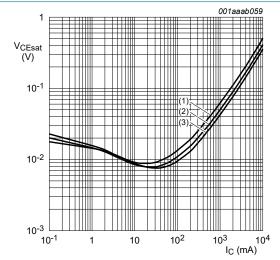


$$V_{CF} = 2 V$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 6. Base-emitter voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

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<sup>3</sup> 10<sup>4</sup> I<sub>C</sub> (mA)

10<sup>3</sup>

#### 80 V, 4 A NPN low VCEsat transistor

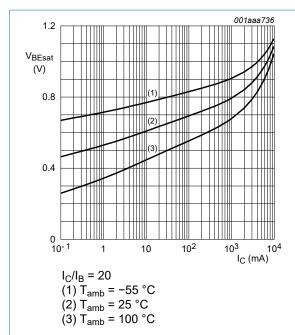
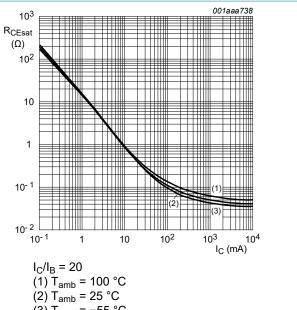


Fig. 9. collector current; typical values



(1)  $T_{amb} = 100 \text{ °C}$ (2)  $T_{amb} = 25 \text{ °C}$ (3)  $T_{amb} = -55 \text{ °C}$ 

Base-emitter saturation voltage as a function of Fig. 10. Equivalent on-resistance as a function of collector current; typical values

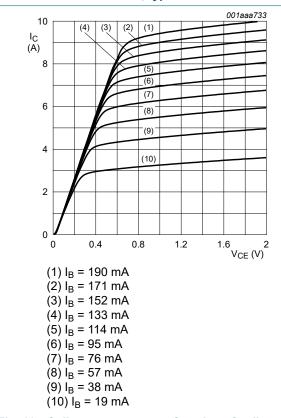


Fig. 11. Collector current as a function of collectoremitter voltage; typical values

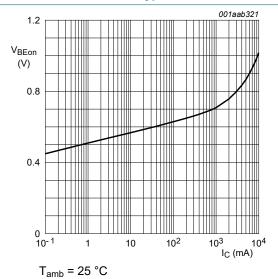


Fig. 12. Base-emitter turn-on voltage as a function of collector current; typical values

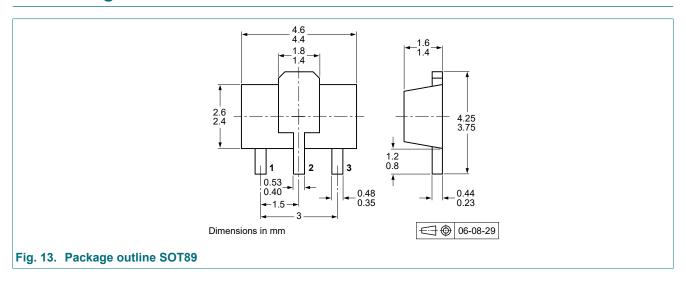
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## 11. Test information

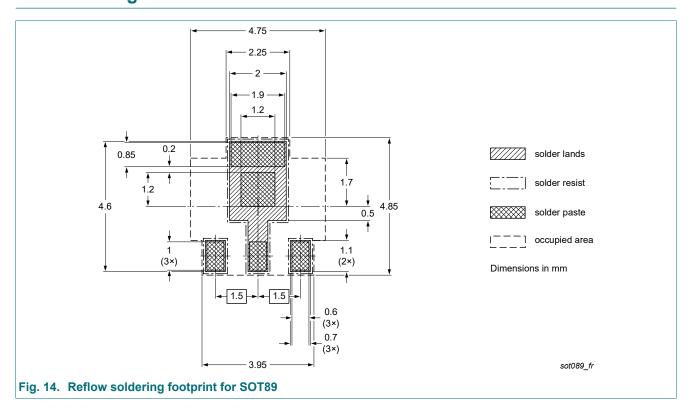
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

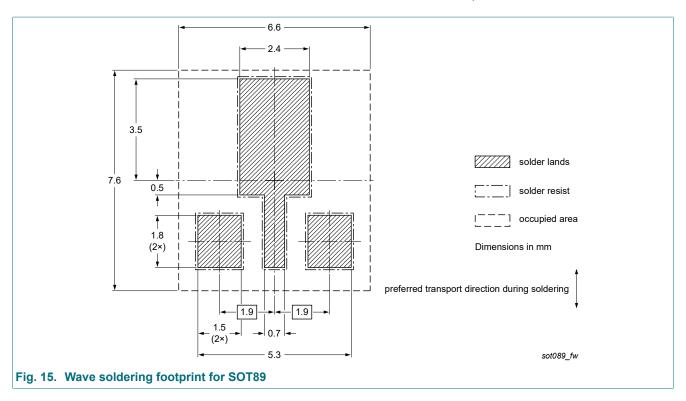
# 12. Package outline



# 13. Soldering



## 80 V, 4 A NPN low VCEsat transistor



80 V, 4 A NPN low VCEsat transistor

# 14. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4480X-Q v.1	20240605	Product data sheet	-	-

## 80 V, 4 A NPN low VCEsat transistor

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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